



N-Channel Silicon MOSFET High-Voltage, High-Speed Switching Applications

Features

- Low ON-resistance, low input capacitance, ultrahigh-speed switching.
- High reliability (Adoption of HVP process).
- Micaless package facilitating mounting.
- · Avalanche resistance guarantee.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		1500	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID*		2	Α
Drain Current (Pulse)	IDP		4	А
Allowable Power Dissipation	PD		2.0	W
		Tc=25°C	35	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Enargy (Single Pulse) *1	EAS		42	mJ
Avalanche Current *2	IAV		2	А

*1 VDD=99V, L=20mH, IAV=2A

*2 L≤20mH, single pulse

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	1500			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =1200V, V _{GS} =0V			100	μΑ
Gate-to-Source Leakage Current	IGSS	$V_{GS}=\pm 16V, V_{DS}=0V$			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	2.5		3.5	V
Forward Transfer Admittance	yfs	V _{DS} =20V, I _D =1A	0.7	1.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)	ID=1A, VGS=10V		10	13	Ω

Marking: K3745

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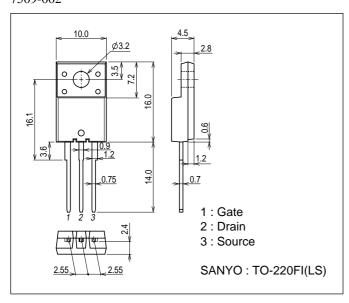
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Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	VDS=30V, f=1MHz		380		pF
Output Capacitance	Coss	V _{DS} =30V, f=1MHz		70		pF
Reverse Transfer Capacitance	Crss	VDS=30V, f=1MHz		40		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		12		ns
Rise Time	tr	See specified Test Circuit.		37		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		152		ns
Fall Time	tf	See specified Test Circuit.		59		ns
Total Gate Charge	Qg	V _{DS} =200V, V _{GS} =10V, I _D =2A		37.5		nC
Gate-to-Source Charge	Qgs	VDS=200V, VGS=10V, ID=2A		2.7		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =200V, V _{GS} =10V, I _D =2A		20		nC
Diode Forward Voltage	VSD	IS=2A, VGS=0V		0.88	1.2	V

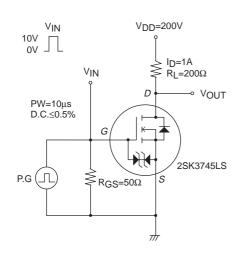
Note) Although the protection diode is contained between gate and source, be careful of handling enough.

Package Dimensions

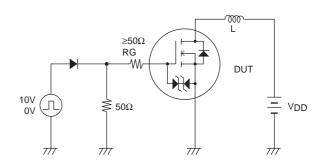
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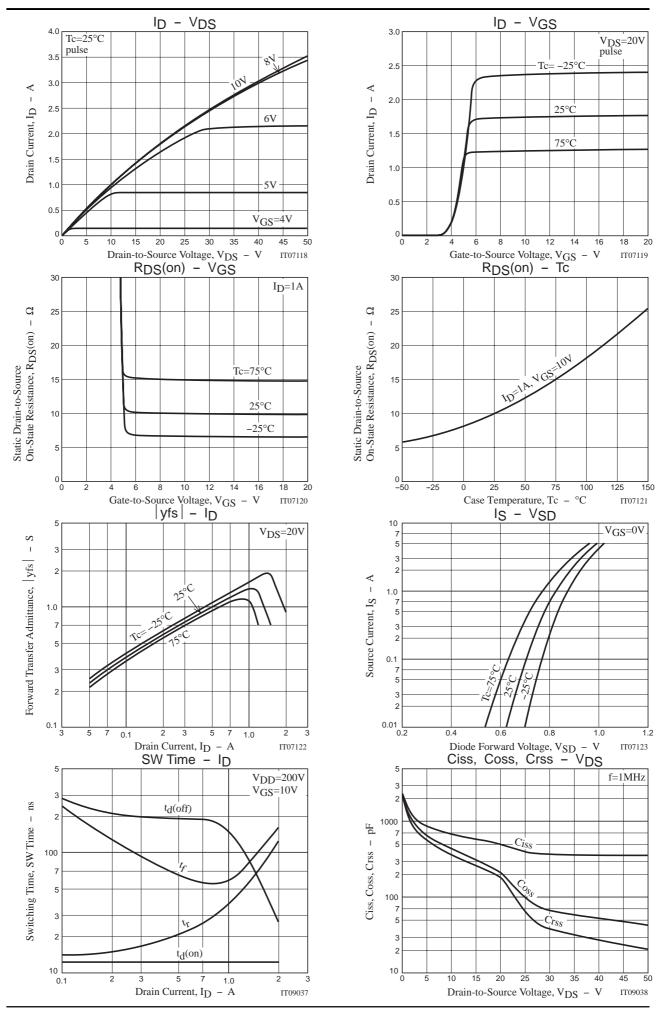


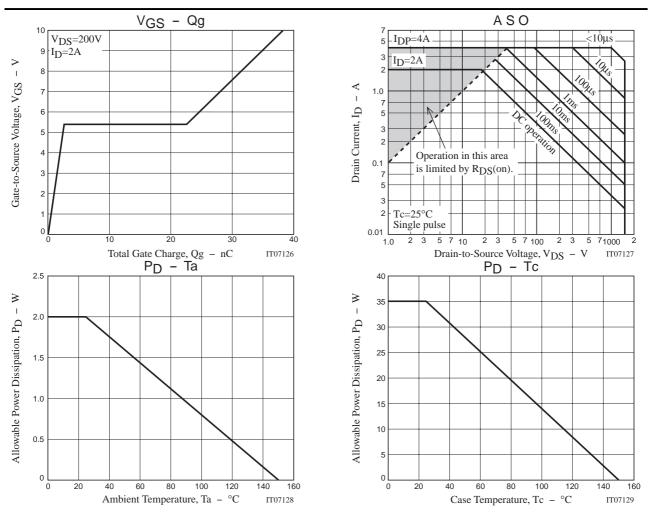
Switching Time Test Circuit



Avalanche Resistance Test Circuit







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